

FORM PTO-1449 SAMUELS, GAUTHIER & STEVENS LLP
(Rev. 5/92) 225 Franklin Street, Boston, MA 02110
Telephone: (617) 426-9180 ..

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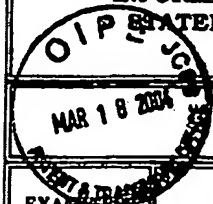
Zhang et al.
APPLICANT

2816
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07/16/2003
FILING DATE

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U.S. PATENT DOCUMENTS

| EXAMINER INITIAL | | DOCUMENT NUMBER | DATE | NAME | CLASS | SUBCLASS | FILING DATE IF APPROPRIATE |
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FOREIGN PATENT DOCUMENTS

| EXAMINER INITIAL | | DOCUMENT NUMBER | DATE | COUNTRY | CLASS | SUBCLASS | TRANSLATION YES NO |
|---------------------|----|--------------------|------------|---------|-------|----------|-----------------------|
| AT | AG | WO 02/067451 | 08/29/2002 | PCT | | | YES (Abstract only) |
| | AH | 0 700 161 A2 | 03/06/1999 | EP | | | YES |
| | AI | 09238059 | 09/09/1997 | JP | | | YES (Abstract only) |

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

| EXAMINER INITIAL | | |
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| AT | AG 0766396 | 04/02/1997 | EP | | | YES |
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| AT | AJ | "Voltage-Tolerant Monolithic L-Band GaAs SPDT Switch," Cooper et al., <i>IEEE MTT-S Digest</i> (1989). No month |
| AT | AK | "A Dual-Gate Shorted-Anode Silicon-on-Insulator Lateral Insulated Gate Bipolar Transistor with Floating Ohmic Contact for Suppressing Snapback and Fast Switching Characteristics," Oh et al., <i>Microelectronics Journal</i> 30 pp. 577-581 (1999). No month |
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| FORM PTO-1449 SAMUELS, GAUTHIER & STEVENS LLP (Rev. 5/92) 225 Franklin Street, Boston, MA 02110 Telephone: (617) 426-9180 | | 7042 ATTORNEY DOCKET NO. <u>Zhang et al.</u> APPLICANT <u>Herewith</u> FILING DATE | Unknown SERIAL NO. 10620395 Unknown GROUP Unknown EXAMINER | | | | |
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| AT | AG | WO 01/67602 | 09/13/2001 | PCT | | | YES |
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| AT | AJ | "High-Performance GaAs Switch IC's Fabricated Using MESFET's with Two Kinds of Pinch-Off Voltages and a Symmetrical Pattern Configuration," Uda et al. <i>IEEE Journal of Solid-State Circuits</i> . October 1994. Vol. 29, No. 10. | | | | | |
| | AK | "A Low-Voltage, High-Power T/R-Switch MMIC Using LC Resonators," Tokumitsu et al. <i>IEEE Transactions on Microwave Theory and Techniques</i> . May 1995. Vol. 43, No. 5. | | | | | |
| | AL | "A GaAs High-Power RF Single-Pole Double-Throw Switch IC for Digital Mobile Communication System," Miyatsuji et al. <i>IEEE International Solid-State Circuit Conference</i> . 1994. <i>Norment</i> | | | | | |
| | AM | "Novel High Performance SPDT Power Switches Using Multi-Gate FET's," McGrath et al. <i>IEEE MTT-S Digest</i> . 1991. <i>Norment</i> | | | | | |
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| 0 | AO | "A High Power 2-18 GHz T/R Switch," Schindler et al. <i>IEEE MTT-S Digest</i> . 1990. <i>Norment</i> | | | | | |
| EXAMINER <i>[Signature]</i> | | | | DATE CONSIDERED <i>11/18/04</i> | | | |
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